PA2001

Ultra Linear Driver Amplifier - 1 Watt
1800 to 2000 MHz

Rev. V1

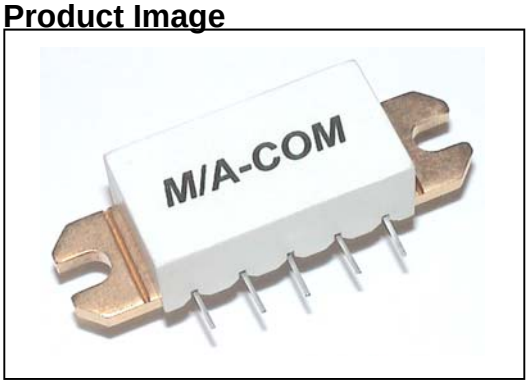
Features

- LOW NOISE FIGURE: 2.0 dB (TYP.)
- GAIN: 21 dB (TYP.)
- HIGH P1dB: +30.3 dBm (TYP.)
- HIGH IP^3: +46.5 dBm (TYP.)
- BROADBAND RESPONSE: 1.5 GHz TO 2.2 GHz (TYP.)

Description

The PA2001 is a is a discrete hybrid design, which uses thick film solder manufacturing processes for accurate performance and high reliability.
This 2 stage GaAS FET transistor design uses feedback loops for flat broadband linear performance, with very low noise figure.
The model is particularly suited for power driver applications used in the base station & repeater infrastructure, and for commercial & military radios.

Product Image



Ordering Information

Part Number	Package
PA2001	Flange Mount Carrier

Absolute Maximum Ratings

Parameter	Absolute Maximum
Storage Temperature	-40ºC to +85ºC
Operation Base Temperature	+85ºC
Max. DC VOltage	+15 Vdc
Max. Continuous RF Input Power	+15 dBm

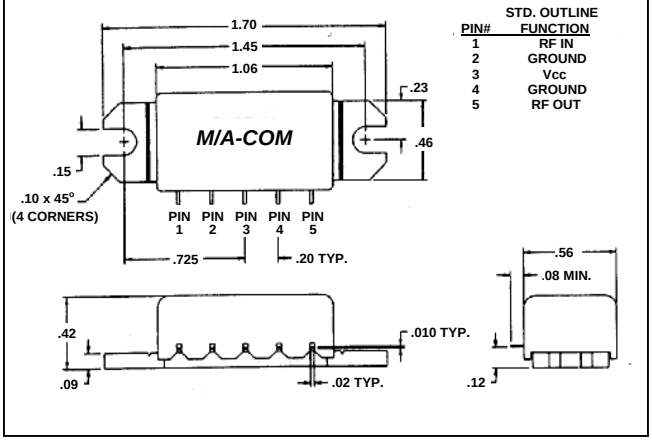
Electrical Specifications: $Z_0 = 50\Omega$, $V_{CC} = +12\ V_{DC}$

Parameter	Units	Typical	Gurarnteed
		25ºC	0ºC to +85ºC
Frequency	MHz	1800-2000	1800-2000
Small Signal Gain (min)	dB	21.0	19.0
Gain Flatness (max)	dB	± 0.2	± 0.4
Noise Figure (max)	dB	2.0	3.5
Reverse Isolation	dB	37.0	
Power Output @ 1.0 dB Comp. (min.)	dBm	+30.3	+29.0
Output IP^3	dBm	+46.5	+43.0
VSWR Input / Output (max.)		1.2:1 / 1.6:1	2.0:1 / 2.0:1
DC Current @ +12 Volts (max.)	mA	345	400

Thermal Data: $V_{CC} = +12\ V_{DC}$

Parameter	Rating
Thermal Resistance θ_{jc}	22ºC/W
Junction Temperature Rise Above Case T_{jc}	51ºC

Outline Drawing: Flange Mount Carrier *



* Dimensions are inches ± 0.015 unless otherwise specified.

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